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BAR DIGIT LED DISPLAY

LBD101/28YGH-XX

DATA SHEET

DOC. NO : QW0905-LBD101/28YGH-XX

REV. : A

DATE : 31 - May - 2005



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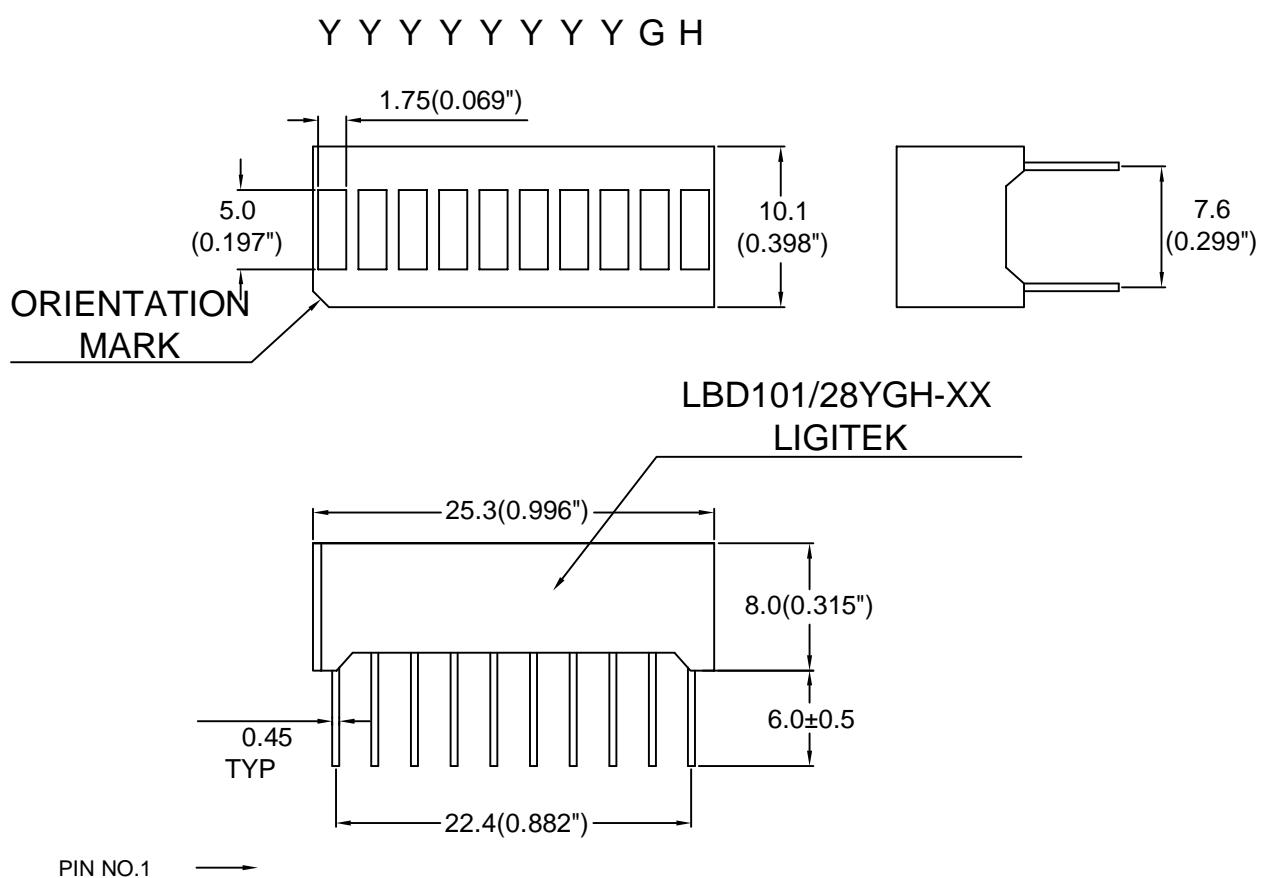
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Package Dimensions



Note : 1.All dimension are in millimeters and (Inch) tolerance is $\pm 0.25\text{mm}$ unless otherwise noted.
2.Specifications are subject to change without notice.



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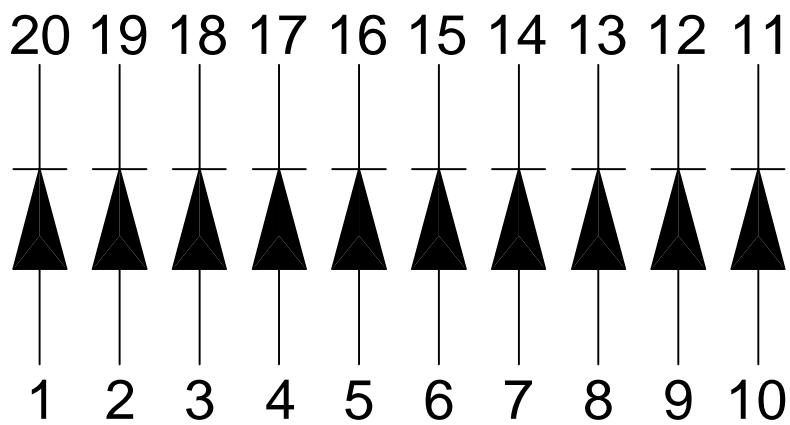
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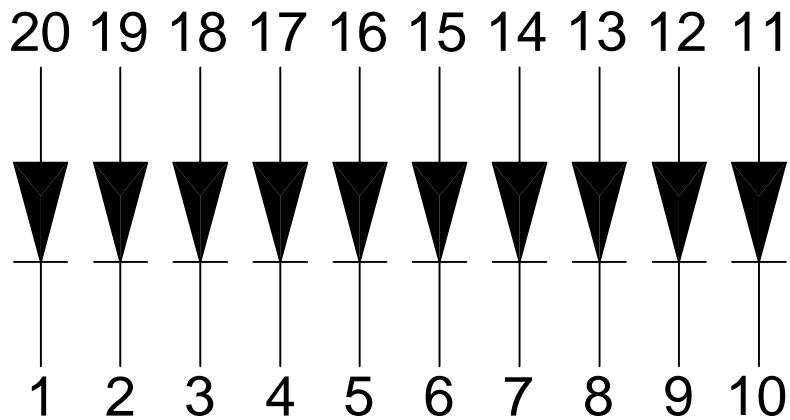
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Internal Circuit Diagram

LBD101/8YGH-XX



LBD102/8YGH-XX





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Electrical Connection

| PIN NO. | LBD101/8YGH-XX | | |
|---------|----------------|-----|---------|
| 1. | Anode | 11. | Cathode |
| 2. | Anode | 12. | Cathode |
| 3. | Anode | 13. | Cathode |
| 4. | Anode | 14. | Cathode |
| 5. | Anode | 15. | Cathode |
| 6. | Anode | 16. | Cathode |
| 7. | Anode | 17. | Cathode |
| 8. | Anode | 18. | Cathode |
| 9. | Anode | 19. | Cathode |
| 10. | Anode | 20. | Cathode |

| PIN NO. | LBD102/8YGH-XX | | |
|---------|----------------|-----|-------|
| 1. | Cathode | 11. | Anode |
| 2. | Cathode | 12. | Anode |
| 3. | Cathode | 13. | Anode |
| 4. | Cathode | 14. | Anode |
| 5. | Cathode | 15. | Anode |
| 6. | Cathode | 16. | Anode |
| 7. | Cathode | 17. | Anode |
| 8. | Cathode | 18. | Anode |
| 9. | Cathode | 19. | Anode |
| 10. | Cathode | 20. | Anode |



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Absolute Maximum Ratings at Ta=25

| Parameter | Symbol | Ratings | | | UNIT |
|---|------------------|-----------|-----|----|------|
| | | Y | G | H | |
| Forward Current Per Chip | I _F | 20 | 30 | 15 | mA |
| Peak Forward Current Per Chip (Duty 1/10,0.1ms Pulse Width) | I _{FP} | 80 | 120 | 60 | mA |
| Power Dissipation Per Chip | P _D | 60 | 100 | 40 | mW |
| Reverse Current Per Any Chip | I _r | 10 | 10 | 10 | μA |
| Operating Temperature | T _{opr} | -25 ~ +85 | | | |
| Storage Temperature | T _{stg} | -25 ~ +85 | | | |
| Solder Temperature 1-16 Inch Below Seating Plane For 3 Seconds At 260 | | | | | |

Part Selection And Application Information(Ratings at 25)

| PART NO | CHIP | | common cathode or anode | P (nm) | (nm) | Electrical | | | | IV-M | |
|-----------------|-----------|---------|-------------------------|--------|------|------------|------|----------------------|------|------|-----|
| | | | | | | Vf(v) | | I _v (mcd) | | | |
| | Material | Emitted | | | | Min. | Typ. | Max. | Min. | Typ. | |
| LBD101/28YGH-XX | GaAsP/GaP | Yellow | Common Cathode | 585 | 35 | 1.7 | 2.1 | 2.6 | 1.75 | 3.05 | 2:1 |
| | GaP | Green | Common Anode | 565 | 30 | 1.7 | 2.1 | 2.6 | 2.35 | 3.05 | |
| | GaP | Red | | 697 | 90 | 1.7 | 2.1 | 2.6 | 0.5 | 0.9 | |

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.

2. The luminous intensity data did not including ±15% testing tolerance.



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Test Condition For Each Parameter

| Parameter | Symbol | Unit | Test Condition |
|-----------------------------------|-----------|---------|----------------|
| Forward Voltage Per Chip | Vf | volt | If=20mA |
| Luminous Intensity Per Chip | Iv | mcd | If=10mA |
| Peak Wavelength | λ | nm | If=20mA |
| Spectral Line Half-Width | | nm | If=20mA |
| Reverse Current Any Chip | Ir | μ A | Vr=5V |
| Luminous Intensity Matching Ratio | IV-M | | |



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Typical Electro-Optical Characteristics Curve

Y CHIP

Fig.1 Forward current vs. Forward Voltage

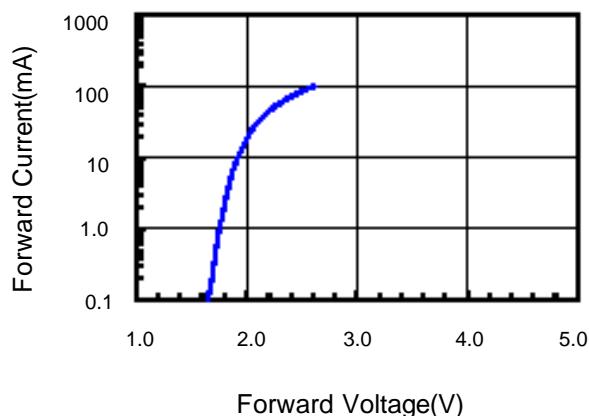


Fig.2 Relative Intensity vs. Forward Current

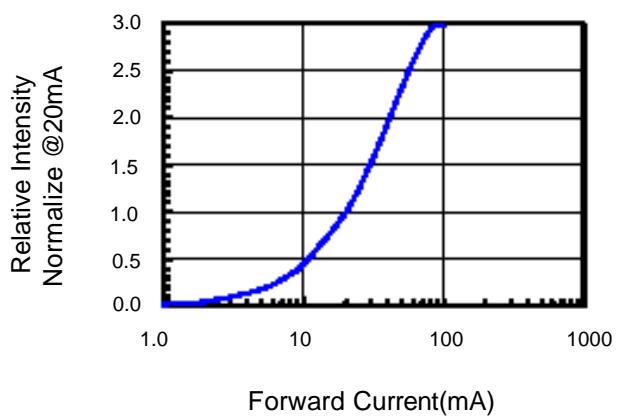


Fig.3 Forward Voltage vs. Temperature

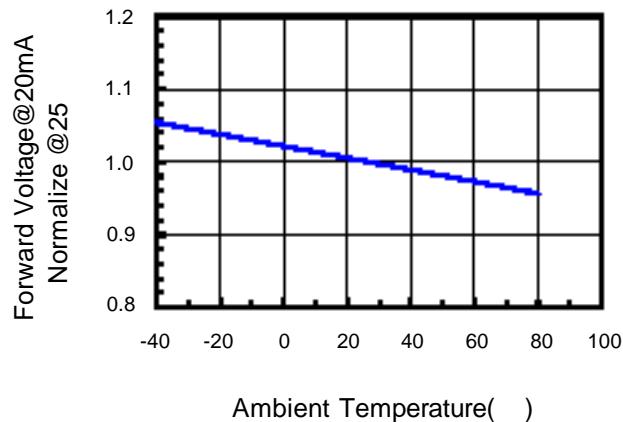


Fig.4 Relative Intensity vs. Temperature

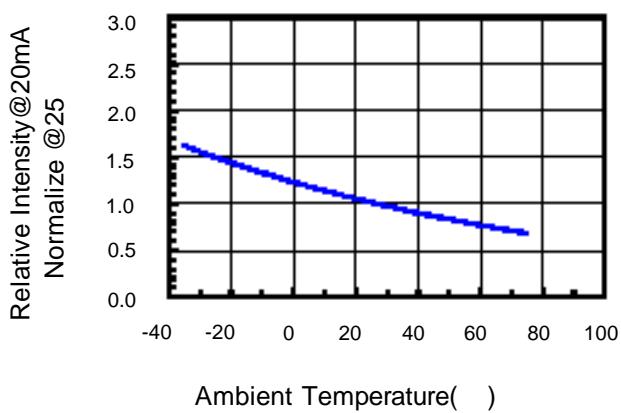
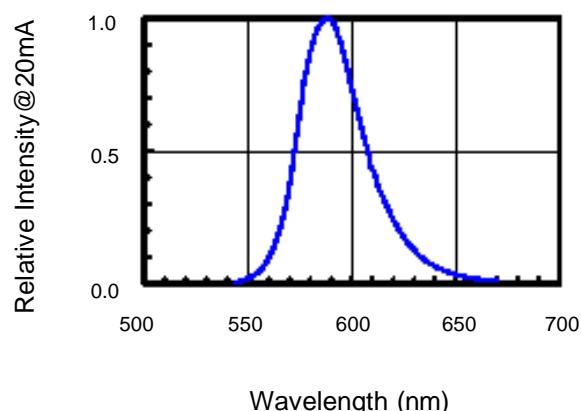


Fig.5 Relative Intensity vs. Wavelength





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Typical Electro-Optical Characteristics Curve

G CHIP

Fig.1 Forward current vs. Forward Voltage

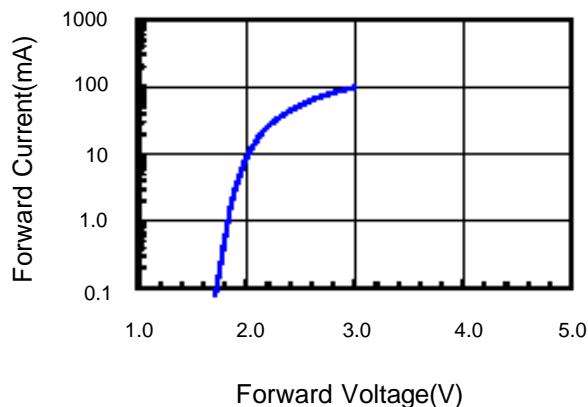


Fig.2 Relative Intensity vs. Forward Current

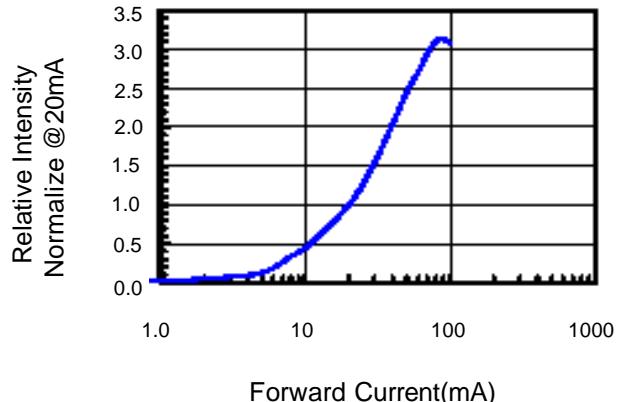


Fig.3 Forward Voltage vs. Temperature

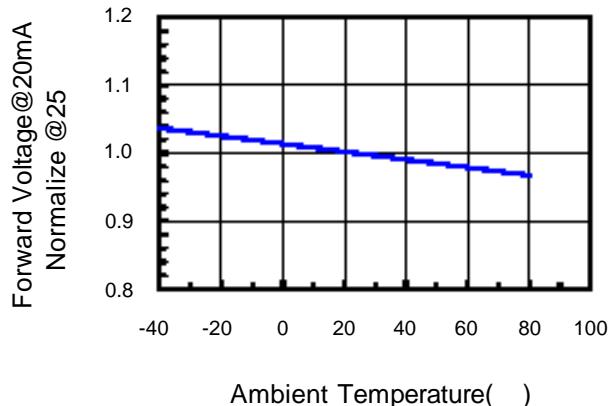


Fig.4 Relative Intensity vs. Temperature

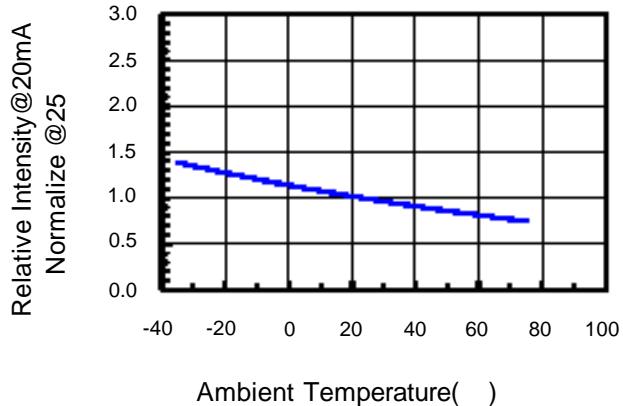
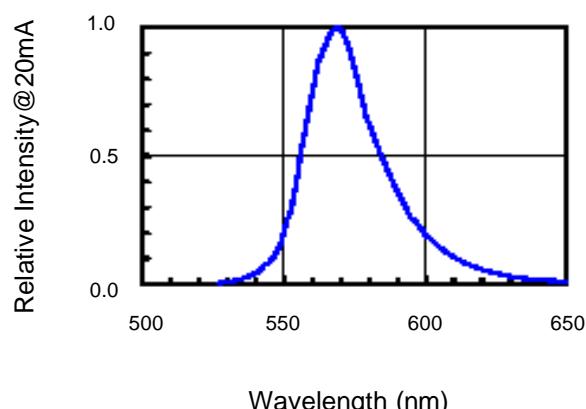


Fig.5 Relative Intensity vs. Wavelength





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Typical Electro-Optical Characteristics Curve

H CHIP

Fig.1 Forward current vs. Forward Voltage

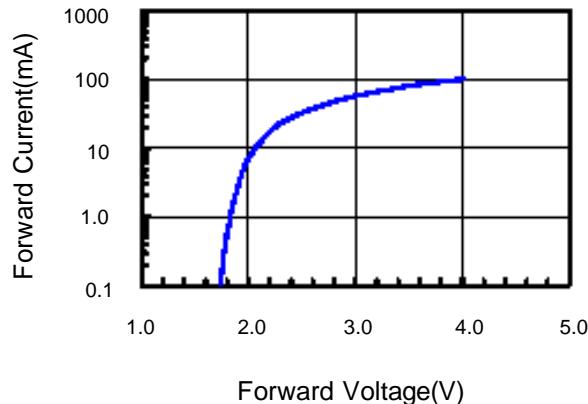


Fig.2 Relative Intensity vs. Forward Current

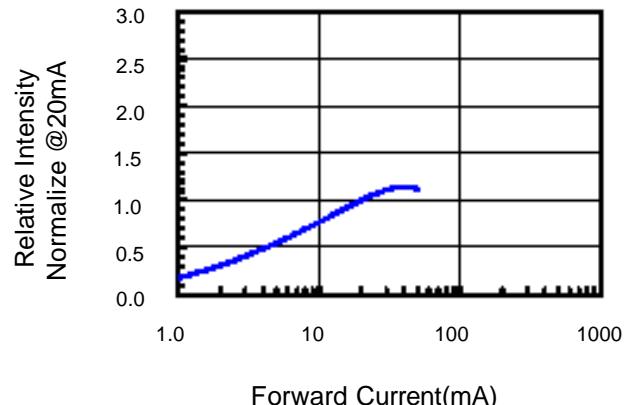


Fig.3 Forward Voltage vs. Temperature

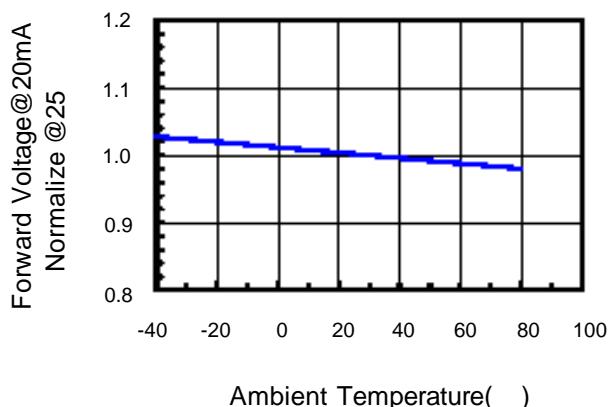


Fig.4 Relative Intensity vs. Temperature

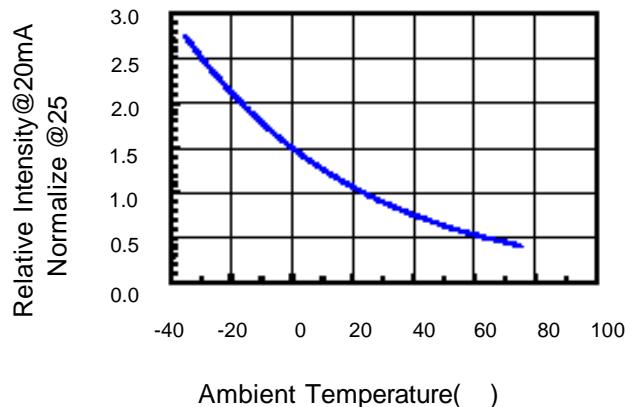
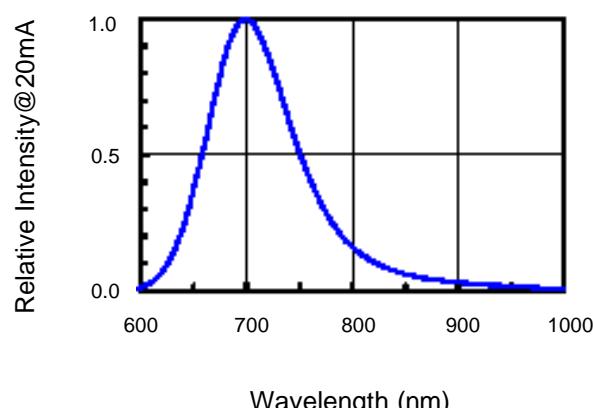


Fig.5 Relative Intensity vs. Wavelength





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Reliability Test:

| Test Item | Test Condition | Description | Reference Standard |
|-------------------------------------|--|---|--|
| Operating Life Test | 1.Under Room Temperature 2.If=10mA 3.t=1000 hrs (-24hrs, +72hrs) | This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed. | MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1 |
| High Temperature Storage Test | 1.Ta=105 ±5 2.t=1000 hrs (-24hrs, +72hrs) | The purpose of this is the resistance of the device which is laid under condition of high temperature for hours. | MIL-STD-883:1008 JIS C 7021: B-10 |
| Low Temperature Storage Test | 1.Ta=-40 ±5 2.t=1000 hrs (-24hrs, +72hrs) | The purpose of this is the resistance of the device which is laid under condition of low temperature for hours. | JIS C 7021: B-12 |
| High Temperature High Humidity Test | 1.Ta=65 ±5 2.RH=90%~95% 3.t=240hrs ±2hrs | The purpose of this test is the resistance of the device under tropical for hours. | MIL-STD-202:103B JIS C 7021: B-11 |
| Thermal Shock Test | 1.Ta=105 ±5 &-40 ±5 (10min) (10min) 2.total 10 cycles | The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature. | MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011 |
| Solder Resistance Test | 1.T.Sol=260 ±5 2.Dwell time= 10 ±1sec. | This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire. | MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1 |
| Solderability Test | 1.T.Sol=230 ±5 2.Dwell time=5 ±1sec | This test intended to see soldering well performed or not. | MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2 |